

# BCO120S100D2

## Silicon Carbide SchottkyDiode

1200V, 100A



bestirpower

### Features

$V_{RRM}$	$I_F$	$T_{J,max}$
1200 V	100 A	175 °C

### Benefits

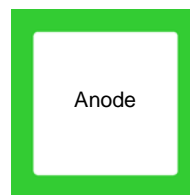
- High-speed switching
- Low heat dissipation requirements
- Reduce size and cost of the system
- High-reliability

- Negligible reverse recovery
- High surge current
- Positive temperature coefficient
- Higher frequency
- Halogen-free / RoHS compliant

### Applications

- Solar inverter
- UPS
- Data Center
- SMPS

### Die Configuration



\*Cathode : Bottom



### Die Mechanical Parameters

Parameter	Typical Value	Unit
Wafer Diameter	6	inch
Die Dimensions (W x L x T)	6228 x 6228 x 200	$\mu\text{m}$
Anode Metallization	(Al)	
Bottom Cathode Metallization	(Ti/Ni/Ag)	
Frontside Passivation	Polymide	
Recommended Source Bond Wire	Al 20mils x 3	ea
Gross Die (Single chip of wafer)	389	ea

### Maximum Ratings ( $T_C = 25^\circ\text{C}$ ) (Note1)

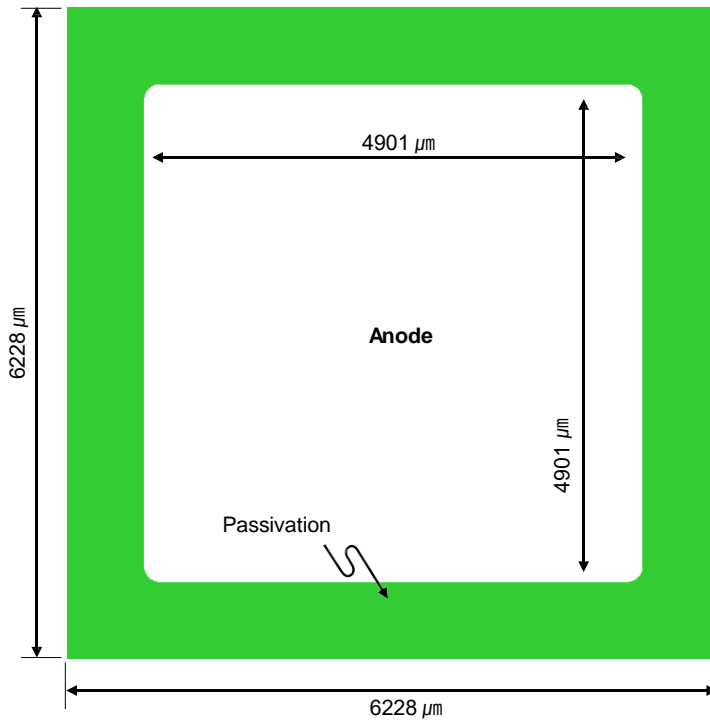
Symbol	Parameter	Test Conditions	Value	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage		1200	V
$I_F$	Continuous Forward Current	$T_C = 140^\circ\text{C}$	100	A
$I_{FSM}$	Non-repetitive Forward Surge Current	$t_p = 10\text{ms}$ , Half sine pulse	500	A
$I_{FRM}$	Repetitive Peak Forward Surge Current	$t_p = 10\text{ms}$ , Half sine pulse	290	A

### Electrical Characteristics ( $T_C = 25^\circ\text{C}$ ) (Note1)

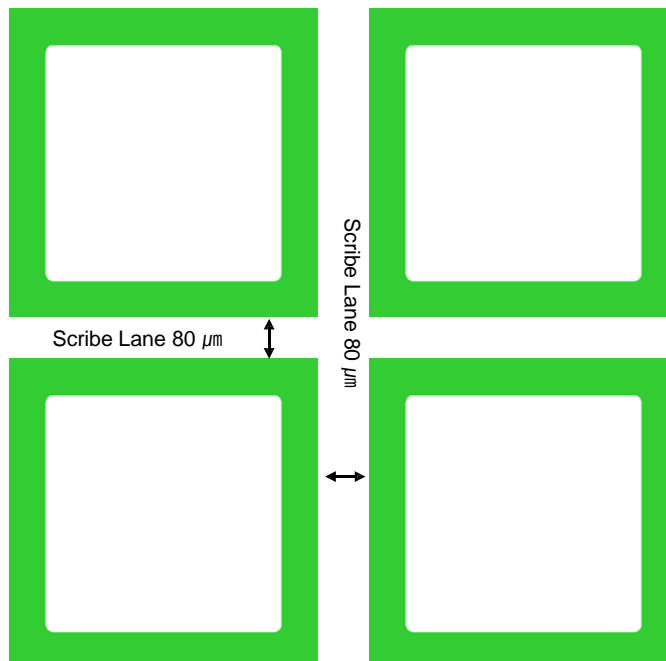
Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
$V_R$	Reverse Blocking Voltage	$I_R = 180 \mu\text{A}$ , $T_C = 25^\circ\text{C}$	1200	-	-	V
$I_R$	Reverse Current	$V_R = 1200 \text{V}$ , $T_C = 25^\circ\text{C}$	-	35	180	$\mu\text{A}$
$V_F$	Forward Voltage	$I_F = 100 \text{A}$ , $T_C = 25^\circ\text{C}$	-	1.65	1.80	V

1. Base on TO247-2 package.

### Die Layout



### Wafer Sawing Information



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